NSN 5961-01-352-6934

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-352-6934 **Inclosure Material:** Metal and ceramic **Overall Length:** 0.598 inches **Overall Diameter:** 1.650 inches **Mounting Method:** Compression **Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1100.0 nonrepetitive peak off-state voltage and 1100.0 nonrepetitive peak reverse voltage and 1000.0 repetitive peak off-state voltage and 1000.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 6500.00 amperes peak forward surge current nanoamperes and 665.00 amperes forward current, total rms horsepower metric **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 quick disconnect, male and 2 case Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: A110a0